FFPF10UP60S

10 A, 600 V Ultrafast Diode

Description

The FFPF10UP60S is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.

Features

- Ultrafast Recovery, $t_{RR} = 40 \text{ ns}$ (@ $I_F = 1 \text{ A}$)
- Max Forward Voltage, $V_F = 2.2 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- General Purpose
- SMPS, Power Switching Circuits
- Free-Wheeling Diode for Motor Application
- Welder, UPS

ABSOLUTE MAXIMUM RATINGS

 $T_C = 25^{\circ}C$ unless otherwise noted

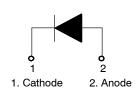
Symbol	Parameter	Rating	Unit		
VRRM	Peak Repetitive Reverse Voltage	600	V		
Vrwm	Working Peak Reverse Voltage 600				
lf(AV)	Average Rectified Forward Current @ T _C = 60°C				
IFSM	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	50	Α		
TJ, Tsтg	G Operating Junction and Storage Temperature		°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

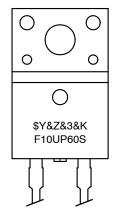
www.onsemi.com





TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z&3 = Data Code (Year & Week)

&K = Lot

F10UP60S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF10UP60S

THERMAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Unit
Rejc	Maximum Thermal Resistance, Junction to Case	4.5	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF10UP60STU	F10UP60S	TO-220F-2L	Tube	N/A	N/A	30

ELECTRICAL CHARACTERISTICS T_C = 25°C unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max.	Unit
V _F (Note 1)	Maximum Instantaneous Forward Voltage $I_F = 10 \text{ A}$ $I_F = 10 \text{ A}$	T _C = 25°C T _C = 100°C		- -	2.2 2.0	٧
I _R (Note 1)	Maximum Instantaneous Reverse Current @ rated V _R	T _C = 25°C T _C = 100°C		- -	100 500	μΑ
t _{RR}	$I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_R = 30 \text{ V}$	T _C = 25°C	-	_	25	ns
t _{RR} I _{RR} Q _{RR}	Reverse Recovery Time Reverse Recovery Current Reverse Recovery Charge (I _F = 8 A, di _F /dt = 200 A/µs, V _R = 390 V)		- - -	34 1.0 17	40 1.5 30	ns A nC
t _{RR}	Maximum Reverse Recovery Time (I_F =10 A, di_F/dt = 200 A/ μ s, V_R = 390 V)		-	58	-	ns
W _{AVL}	Avalanche Energy (L = 40 mH)		20	-	_	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

Test Circuit and Waveforms

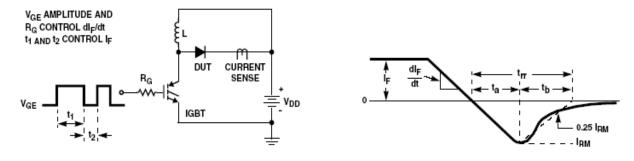


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

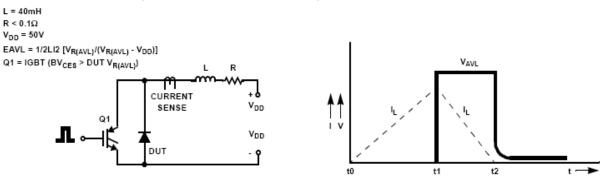
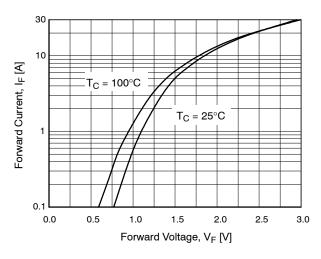


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

FFPF10UP60S

TYPICAL PERFORMANCE CHARACTERISTICS

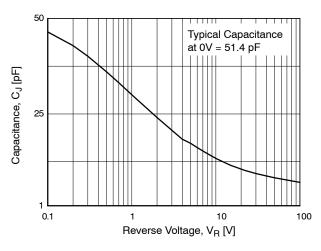
 $T_C = 25^{\circ}C$ unless otherwise noted



1000 100 Reverse Current, IR [µA] T_C = 100°C 10 T_C = 25°C 0.01 1E-3 0 100 200 300 400 500 600 Reverse Voltage, V_R [V]

Figure 3. Typical Forward Voltage Drop

Figure 4. Typical Reverse Current



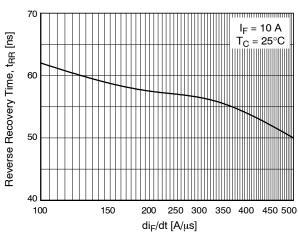
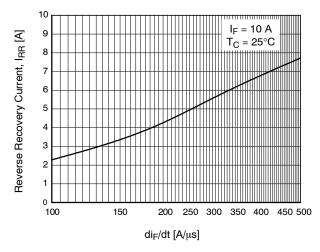


Figure 5. Typical Junction Capacitance

Figure 6. Typical Reverse Recovery Time



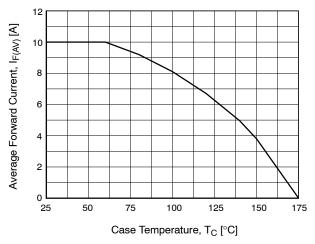
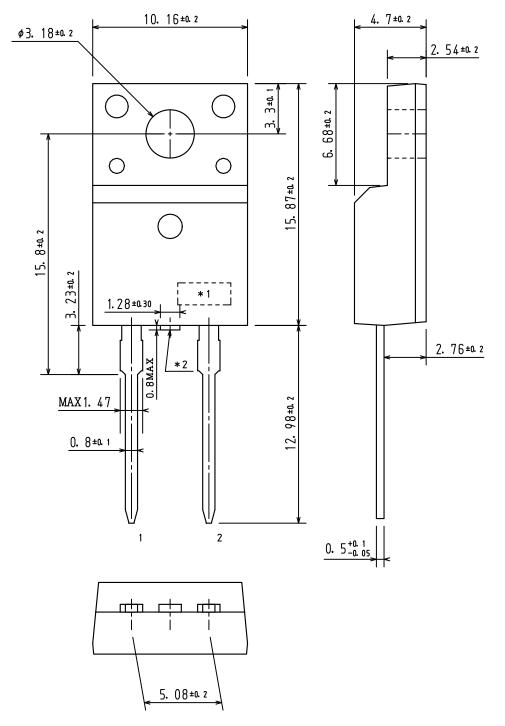


Figure 7. Typical Reverse Recovery Current

Figure 8. Forward Current Derating Curve

TO-220 Fullpack, 2-Lead / TO-220F-2FS CASE 221AS ISSUE O

DATE 29 FEB 2012



DOCUMENT NUMBER:	98AON67438E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-220 FULLPACK, 2-LEAD / TO-220F-2FS		PAGE 1 OF 1	

ON Semiconductor and III are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative